

Substitutional and Interstitial Diffusion in α_2 -Ti₃Al(O)

E. Copland¹, D. J. Young², B. Gleeson³, N. Jacobson⁴

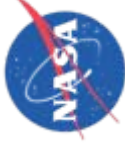
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The reaction between Al₂O₃ and α_2 -Ti₃Al was studied with a series of Al₂O₃/ α_2 -Ti₃Al multiphase diffusion couples annealed at 900, 1000 and 1100°C. The diffusion-paths were found to strongly depend on α_2 -Ti₃Al(O) composition. For alloys with low oxygen concentrations the reaction involved the reduction of Al₂O₃, the formation of a γ -TiAl reaction-layer and diffusion of Al and O into the α_2 -Ti₃Al substrate. Measured concentration profiles across the interaction-zone showed “up-hill” diffusion of O in α_2 -Ti₃Al(O) indicating a significant thermodynamic interaction between O and Al, Ti or both. Diffusion coefficients for the interstitial O in α_2 -Ti₃Al(O) were determined independently from the interdiffusion of Ti and Al on the substitutional lattice. Diffusion coefficients are reported for α_2 -Ti₃Al(O) as well as γ -TiAl. Interpretation of the results were aided with the subsequent measurement of the activities of Al, Ti and O in α_2 -Ti₃Al(O) by Knudsen effusion-cell mass spectrometry.



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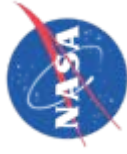
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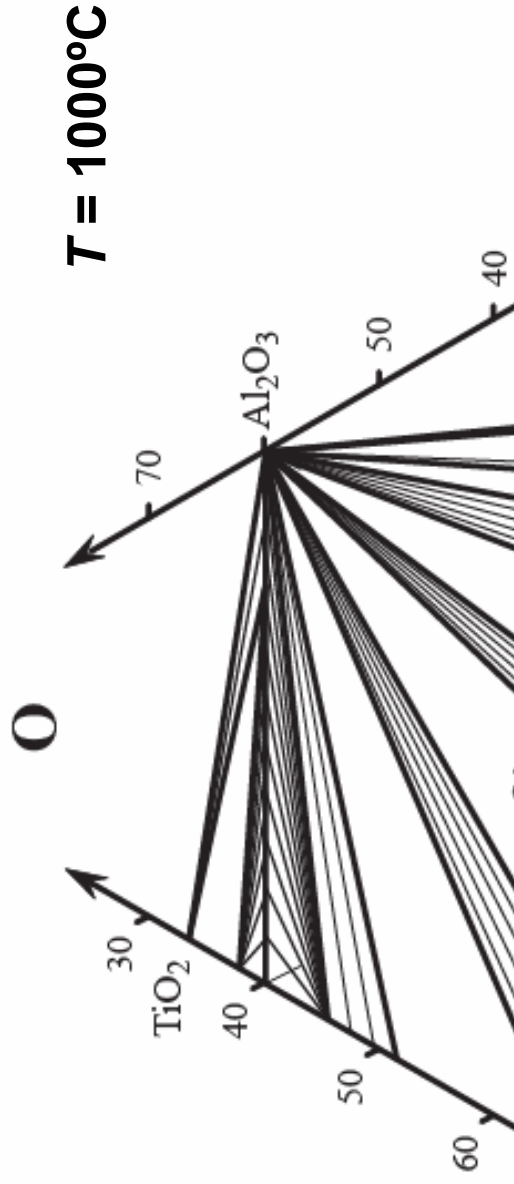
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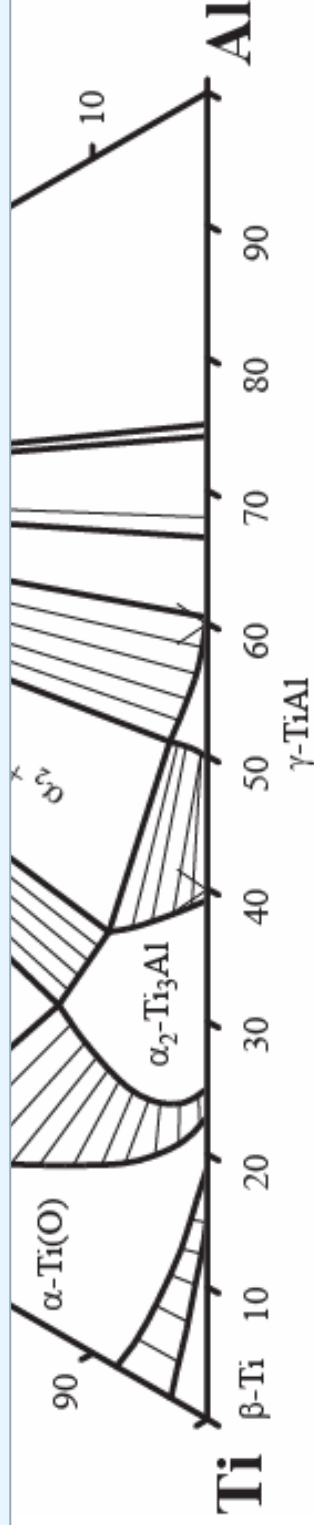


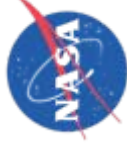
Ti-Al-O system



Al_2O_3 only oxide in equilibrium with $\alpha_2\text{-Ti}_3\text{Al} + \gamma\text{-TiAl}$, but...

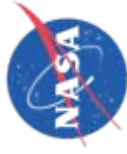
both phases must be saturated with O





outline

- rationale... possible MMC and oxidation of $\alpha_2\text{-Ti}_3\text{Al} + \gamma\text{-TiAl}$
- multi-phase couples: $\alpha_2 / \text{Al}_2\text{O}_3$
 - ↳ results & calculations
- single-phase couples: $\alpha_2(\text{O}) / \alpha_2(\text{O})$
 - ↳ results & calculations
- partial thermodynamic properties in $\alpha_2\text{-Ti}_3\text{Al}(\text{O})$
- summary



multi-phase Ti-Al / Al₂O₃ couples

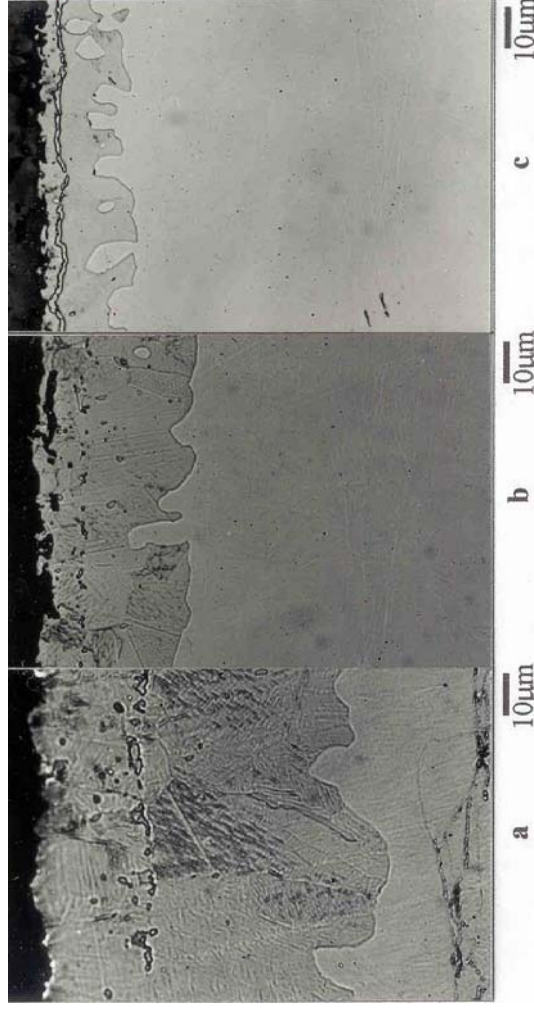
- arc-melted: Al, Ti & TiO₂; annealed at $T = 900, 1000, 1100^{\circ}\text{C}$
- ↳ closed system: Ta-foil (barrier for SiO₂)- in SiO₂ capsule
- HIP bonding (170 MPa, 1100°C for 2 h), poly-crystalline Al₂O₃
- ↳ re-encapsulated, reacted 900, 1000, 1100°C for $t = 20 \sim 500 \text{ h}$
- analysis: metallography, optical, EPMA and micro-hardness

alloy	comp. (at.%)	phase
1 ~ 3	Ti-(49, 52, 55)Al	γ -TiAl ← no reaction, ignore
4	Ti-25Al	α_2 -Ti ₃ Al
5	Ti-32Al	α_2 -Ti ₃ Al
6	Ti-35Al	α_2 -Ti ₃ Al
7	Ti-33.35Al-5O	α_2 -Ti ₃ Al(O)
8	Ti-27Al-10O	α_2 -Ti ₃ Al(O) ← reaction, but ignore
9 ~ 10	Ti-(40, 48)Al	$\alpha_2 + \gamma$

α_2 -Ti₃Al / Al₂O₃ couples

Al₂O₃

marker

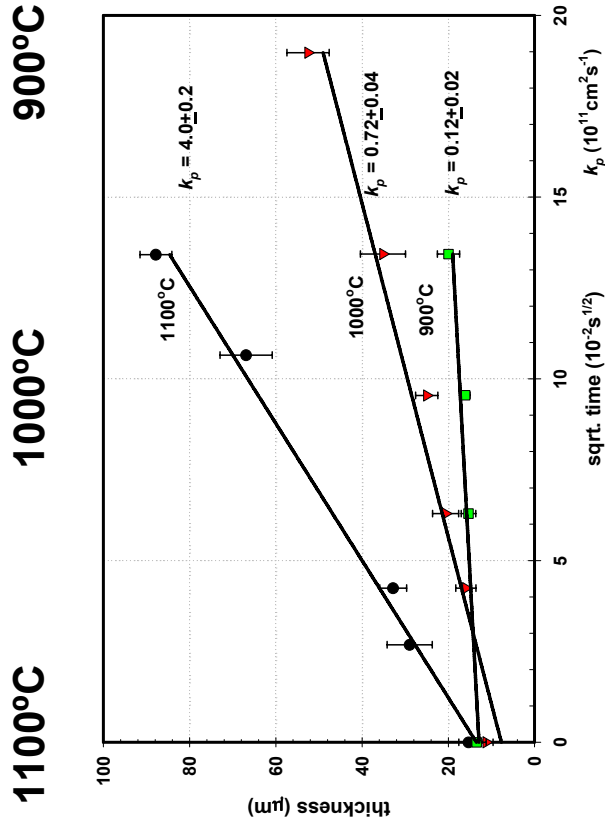


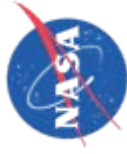
γ -TiAl

Ti-32Al / Al₂O₃,

$t = 500$ h

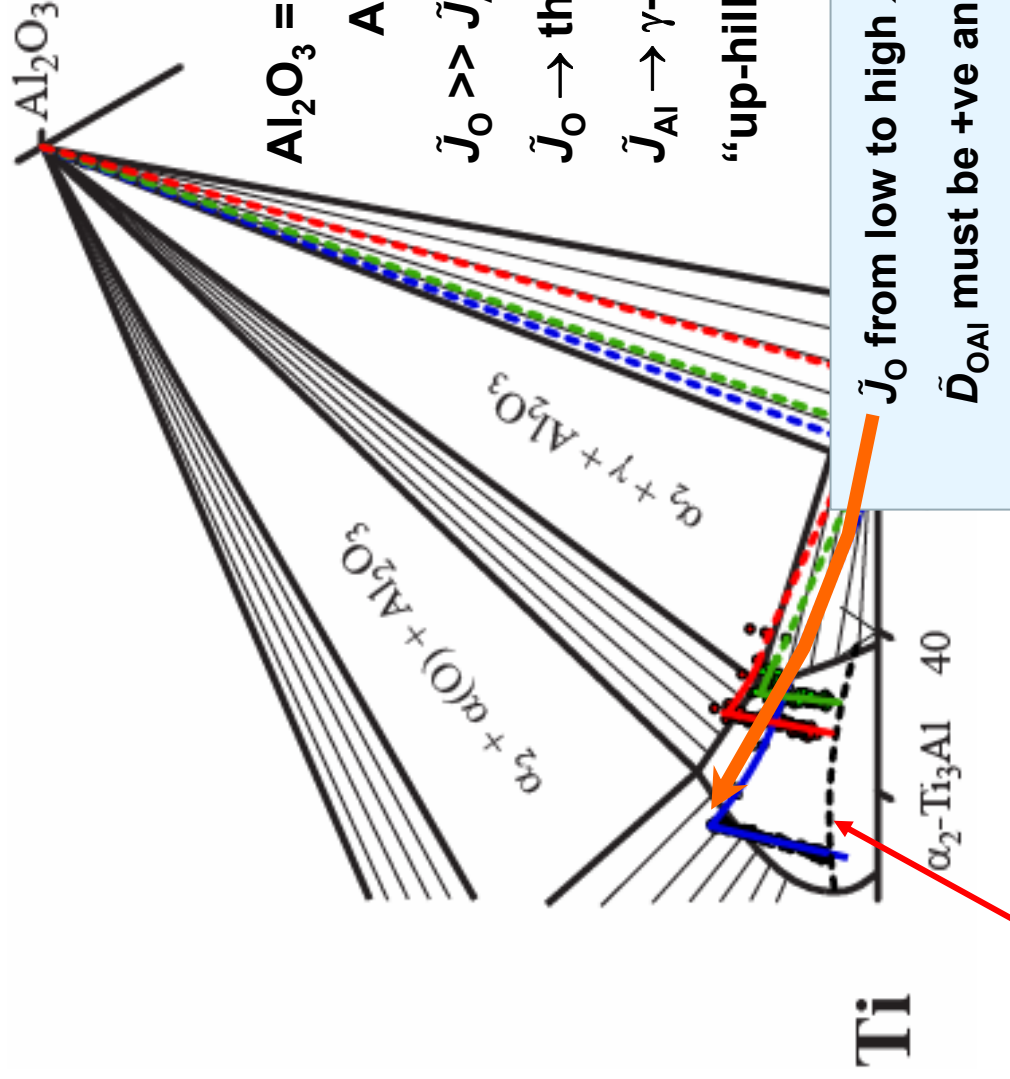
α_2 -Ti₃Al





α_2 -Ti₃Al / Al₂O₃ couples

$T = 1100^\circ\text{C}$



Al, O supplied at activity of γ / Al₂O₃

$\tilde{J}_\text{O} \gg \tilde{J}_\text{Al}$ (from diffusion path)

$\tilde{J}_\text{O} \rightarrow$ through γ -layer into $\alpha_2(\text{O})$

$\tilde{J}_\text{Al} \rightarrow \gamma$ -layer growth and enriches $\alpha_2(\text{O})$

“up-hill” diffusion of O in $\alpha_2(\text{O})$

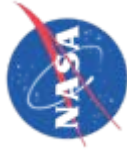
\tilde{J}_O from low to high X_O :

$$\tilde{J}_\text{O} = -\tilde{D}_{\text{Oo}}^{\text{Ti}} \frac{\partial C_\text{O}}{\partial x} - \tilde{D}_{\text{OAl}}^{\text{Ti}} \frac{\partial C_\text{Al}}{\partial x}$$

\tilde{D}_{OAl} must be +ve and significant...

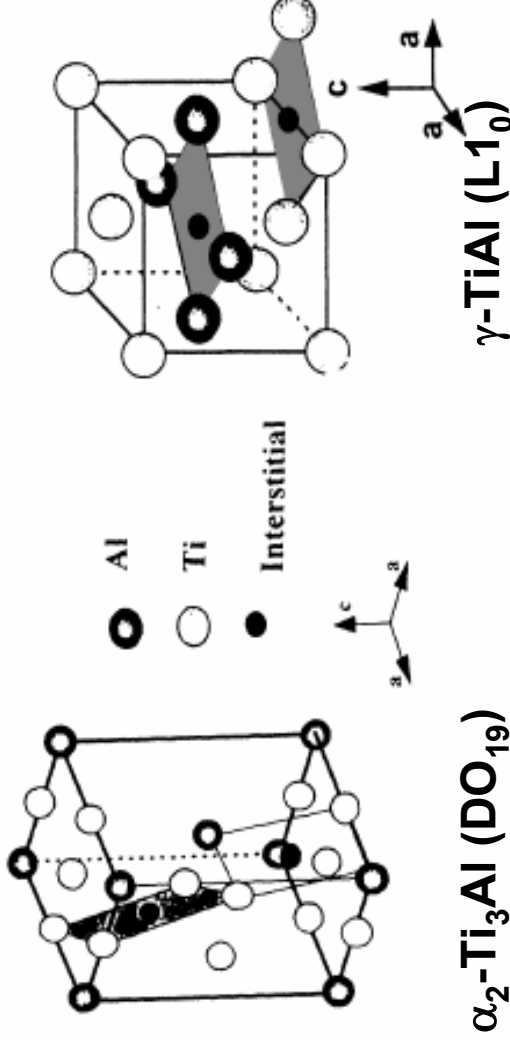
+ve thermodynamic interaction between O and Ti + Al

EPMA error, TiO₂-layer



treating diffusion in Ti-Al-O

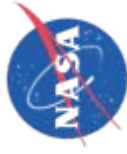
- Ti and Al substitutional; O interstitial, but [OTi₆] only stable sites
- limited kinetic interaction between lattices plus $\tilde{J}_O \gg \tilde{J}_{Al}$, treat:
 - ↳ Ti-Al “pseudo binary” and O “transient equilibrium”



- correct profiles: $r(\text{Ti, Al}) = 1.45, 1.43\text{\AA}$; $V_m(\alpha_2, \gamma) \approx 10.0 \text{ cm}^3\text{mol}^{-1}$

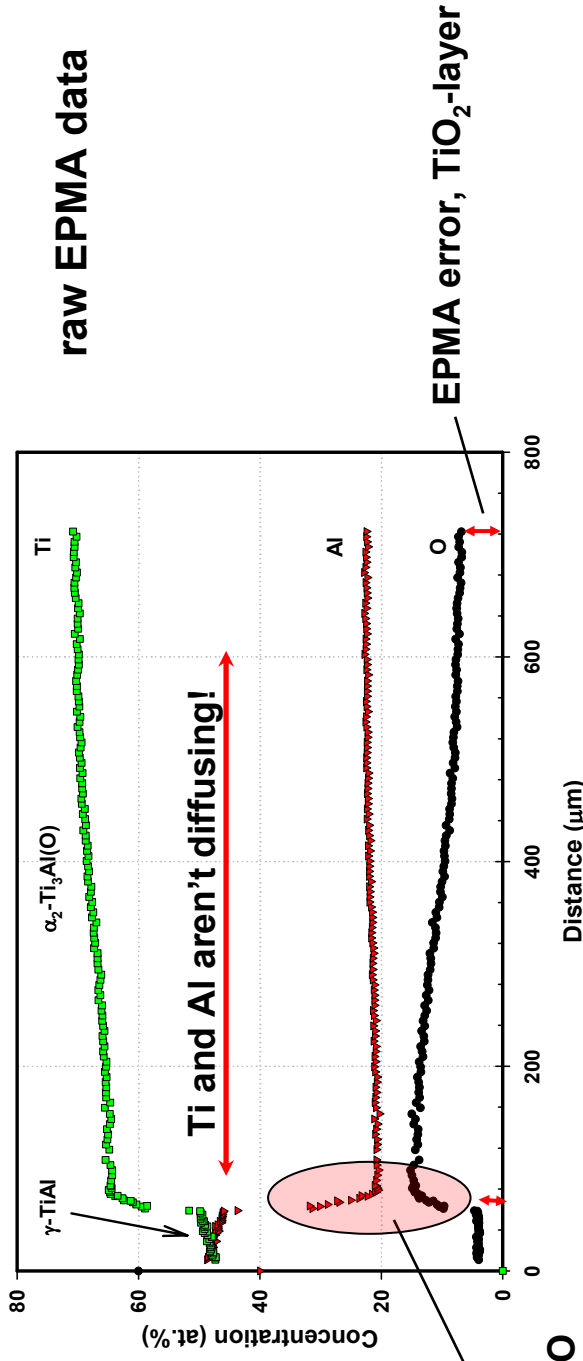
↳ **Ti, Al:** $C_i = (N_i / (N_{\text{Ti}} + N_{\text{Al}})) / V_m$

↳ **O:** $C_o = N_o / V_m$

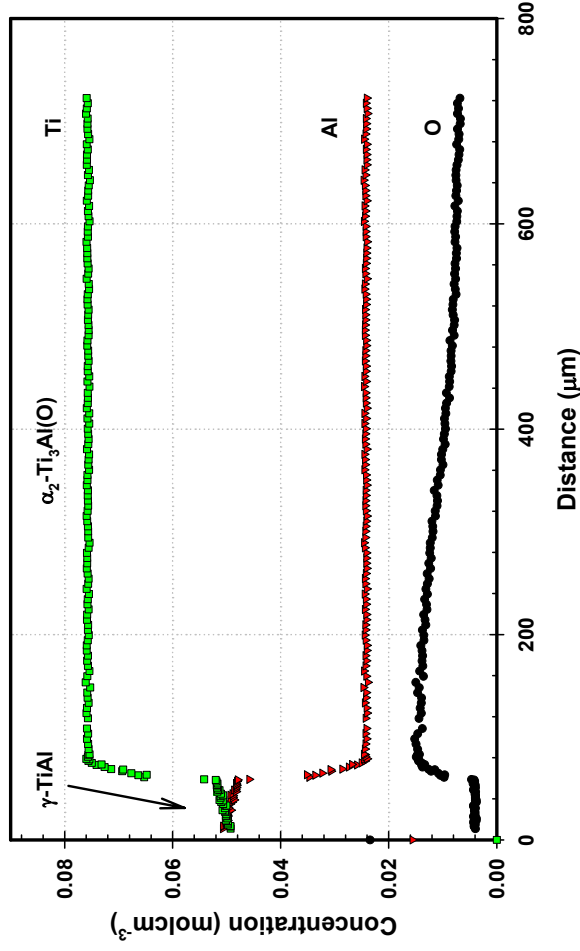


concentration profiles

Al_2O_3 / Ti-25Al
 $T = 1100^\circ\text{C}$, 250 h

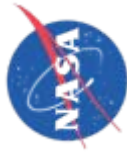


“up-hill” diffusion of O

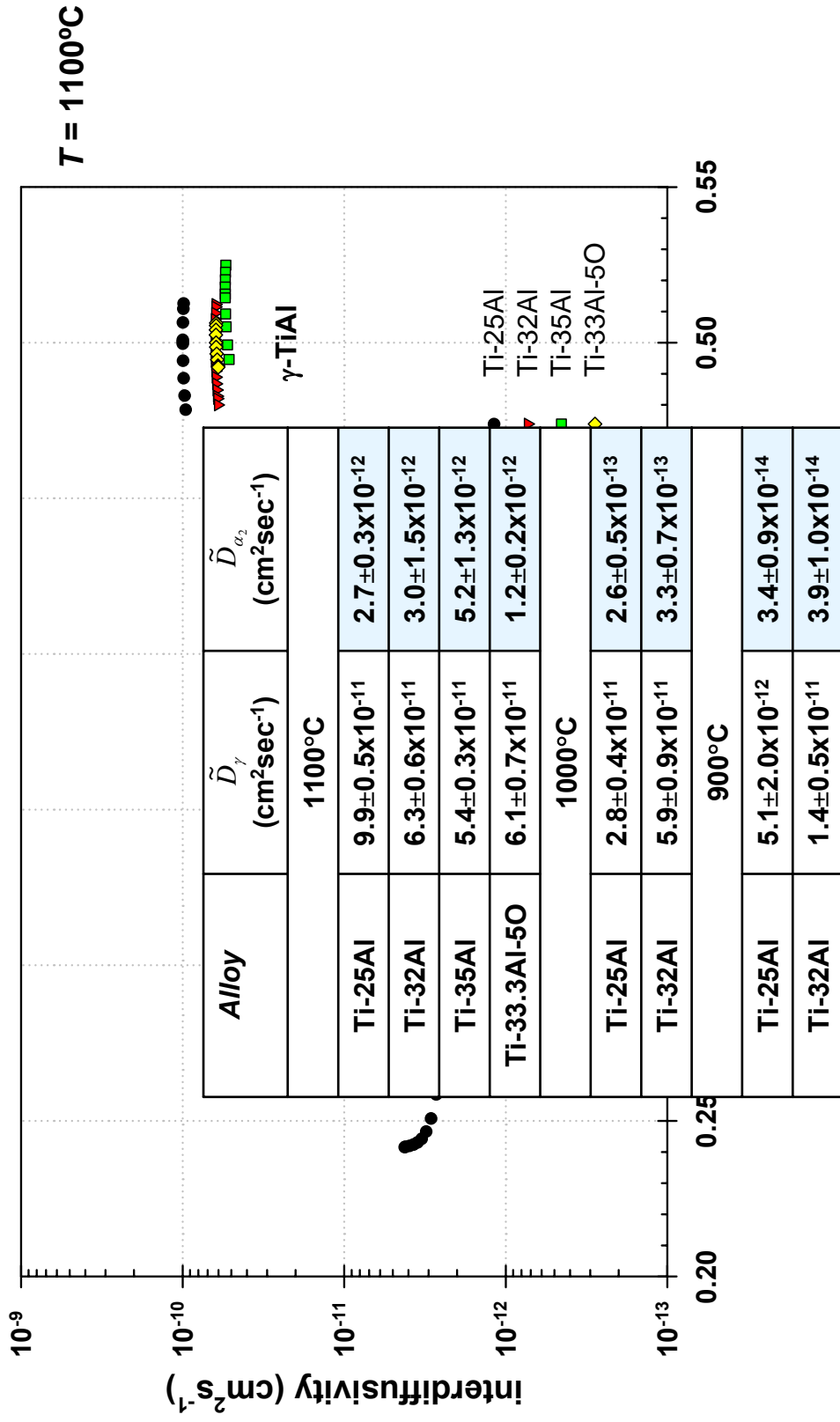


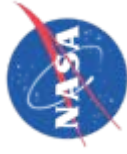
$$C_i = (N_i / (N_{\text{Ti}} + N_{\text{Al}})) / V_m$$

$$C_o = N_o / V_m$$



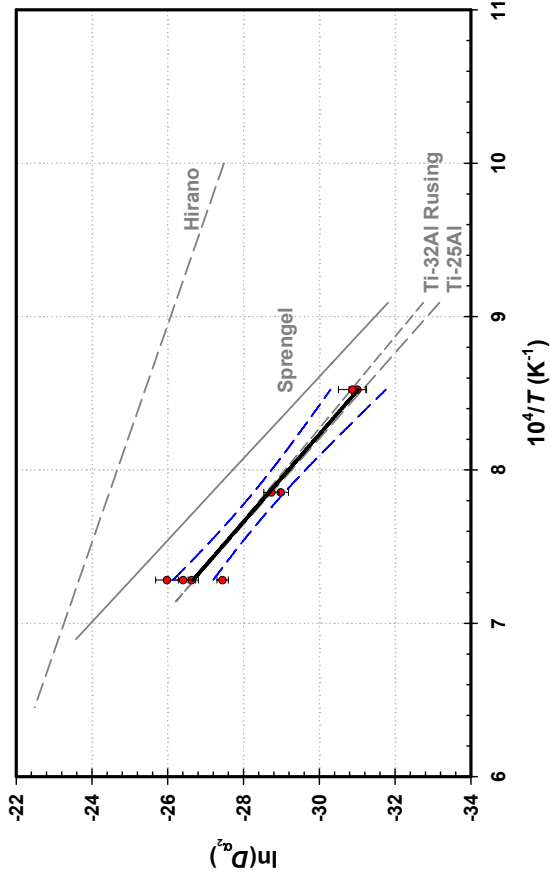
$\tilde{D}(N_i)$ in α_2 -Ti₃Al and γ -TiAl



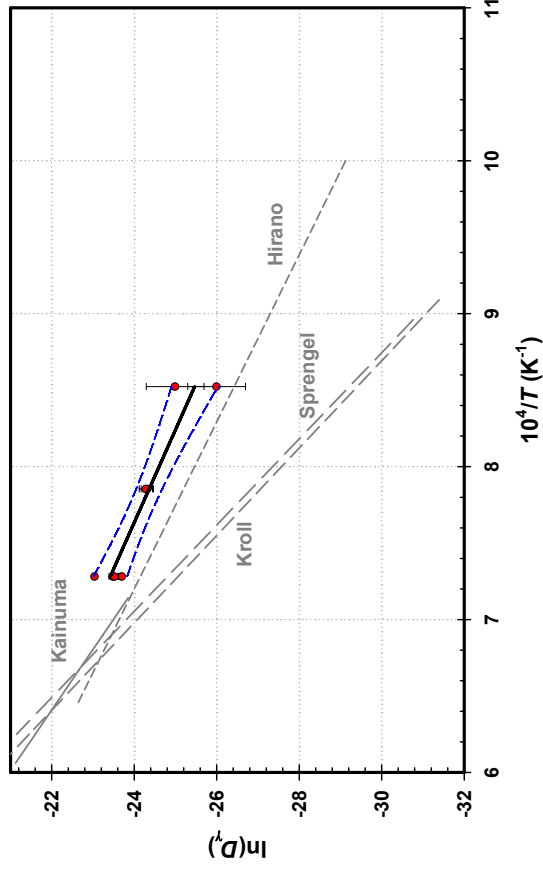


Arrhenius behavior / comparison

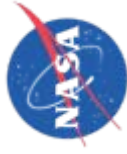
α_2 -Ti₃Al



γ -TiAl



T (°C)	α_2		γ		Method	Reference
	D_O (cm ² s ⁻¹)	E_a (kJmol ⁻¹)	D_O (cm ² s ⁻¹)	E_a (kJmol ⁻¹)		
1169-1366	-	-	3.0×10^{-3}	210	concentration	Kainuma, Inden (1997)
845-1310	10	312 ± 6	2.8	295 ± 10	concentration	Sprengel (1996)
881-1400	-	-	1.5	291 ± 10	tracer	Kroll, (1992)
897-995	0.3	290 ± 15	-	-	tracer	Rüsing, Herzig (1995)
897-995	n/a	≈ 350	-	-	concentration	Rüsing, Herzig (1995)
750-1250	1.5×10^{-6}	117 ± 5	2×10^{-5}	152 ± 2	concentration	Hirano, Iijima (1984)
900-1100	0.3	290 ± 25	1.1×10^{-5}	140 ± 40	concentration	Present results



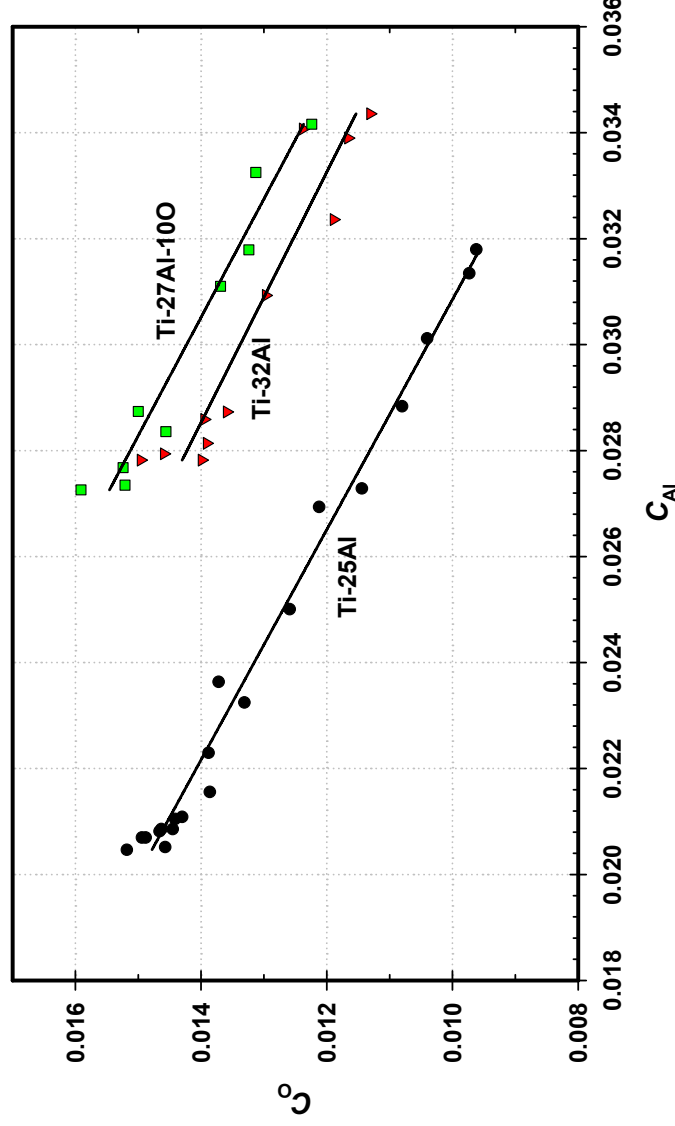
interstitial diffusion of O in α_2 -Ti₃Al

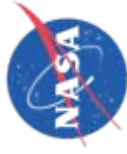
- $\tilde{J}_O \gg \tilde{J}_{(Al,Ti)}$... “transient equilibrium” (Kirkaldy et al. 1958-64)
- O, local equilibrium; redistributes with Ti-Al substitutional lattice

$$\tilde{J}_O^i = -\tilde{D}_{O0}^{Ti} \frac{\partial C_O}{\partial x} - \tilde{D}_{OAl}^{Ti} \frac{\partial C_{Al}}{\partial x} \cong 0$$

$$\frac{\tilde{D}_{OAl}^{Ti}}{\tilde{D}_{O0}^{Ti}} = -\frac{\Delta C_O}{\Delta C_{Al}}$$

- predict interdiffusion coefficient ratio:





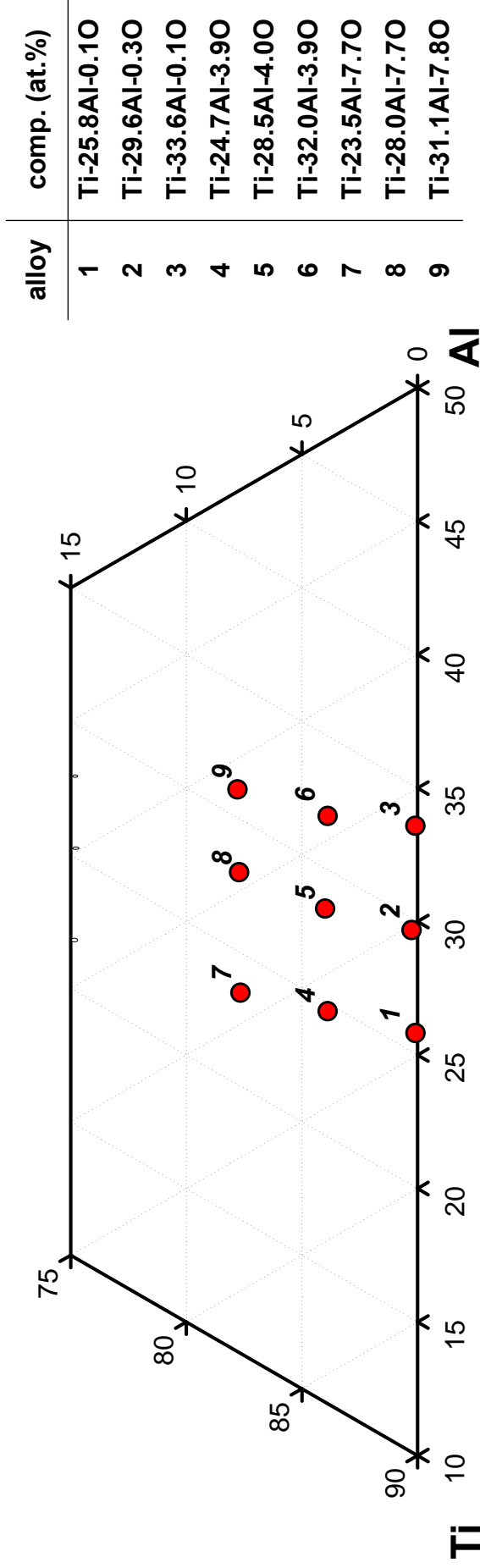
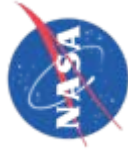
calculated \tilde{D}_{Oo}

- $\tilde{J}_O^i = -\tilde{D}_{Oo}^{Ti} \frac{\partial C_O}{\partial x} - \tilde{D}_{OAl}^{Ti} \frac{\partial C_{Al}}{\partial x}$, no intersecting diffusion paths...
- region of pure O enrichment, $\frac{\partial C_{Al}}{\partial x} = 0 \rightarrow \tilde{J}_O^i = -\tilde{D}_{Oo}^{Ti} \frac{\partial C_O}{\partial x}$
- EPMA and micro-hardness; assume \tilde{D}_{Oo} const. $\frac{C(x,t) - C_s}{C_o - C_s} = erf\left(\frac{x}{2\sqrt{Dt}}\right)$

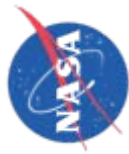
Alloy	\tilde{D}_{Oo}^{Ti} ($10^{-10} \text{cm}^2 \text{s}^{-1}$)			Arrhenius Behaviour	
	1100°C	1000°C	900°C	D_o ($\text{cm}^2 \text{s}^{-1}$)	E_a (kJmole^{-1})
I(Ti-25Al)	4.0±1.0	0.75±0.15	0.2±0.1	0.014	200±23
II(Ti-32Al)	5.5±1.5	0.6±0.15	0.15±0.1	0.60	240±37
III(Ti-35Al)	6.5±1.5	1.0±1.5	0.15±0.1	2.37	252±10

$$\tilde{D}_{Oo} / \tilde{D}_{Al} = 100 \sim 1000$$

single-phase $\alpha_2(\text{O})$ / $\alpha_2(\text{O})$ couples

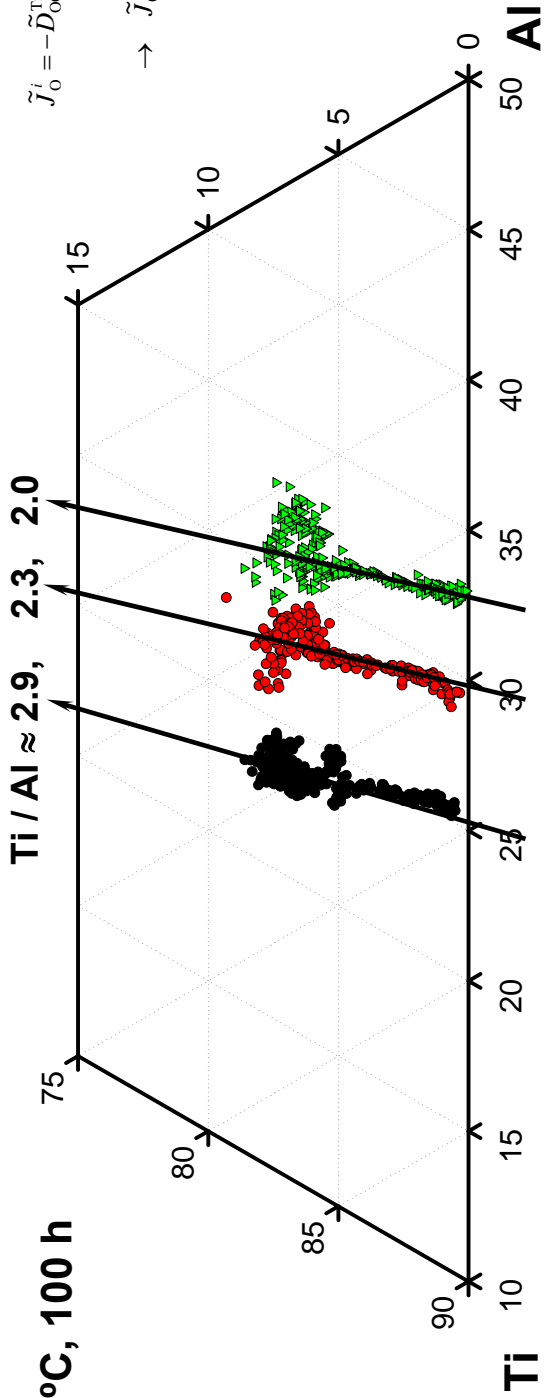


- arc-melted pure-Al, Ti & TiO₂, annealed in closed system:
 - ↳ Ta-foil in SiO₂ capsule
- uni-axial hot press (1100°C for 2 ~ 4 h); T = 1100°C for 100 h
- analysis: metallography, optical & EPMA
 - ↳ used multi-alloy EPMA standard... TiO₂ surface-layer



constant Ti / Al ratio

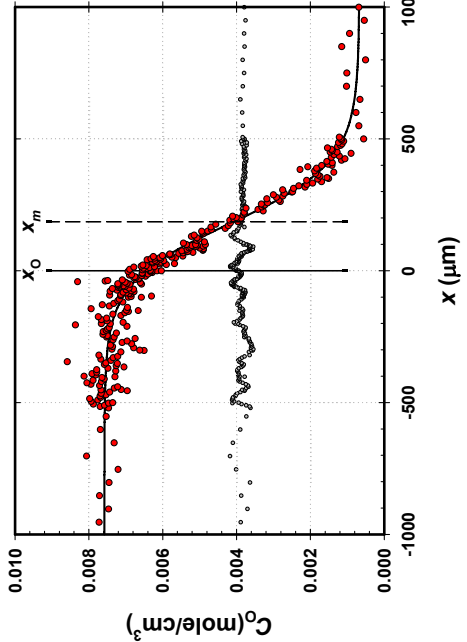
$T = 1100^\circ\text{C}, 100 \text{ h}$



$$\tilde{J}_0^i = -\tilde{D}_{00}^{\text{Ti}} \frac{\partial C_{\text{O}_2}}{\partial x} - \tilde{D}_{\text{OAl}}^{\text{Ti}} \frac{\partial C_{\text{Al}}}{\partial x}$$

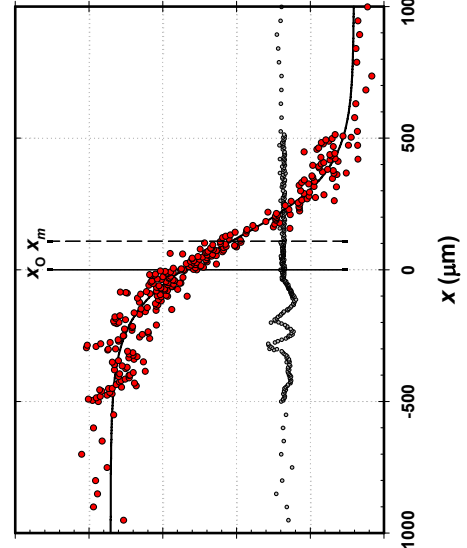
$$\rightarrow \tilde{J}_0^i = -\tilde{D}_{00}^{\text{Ti}} \frac{\partial C_{\text{O}_2}}{\partial x}$$

7 / 1



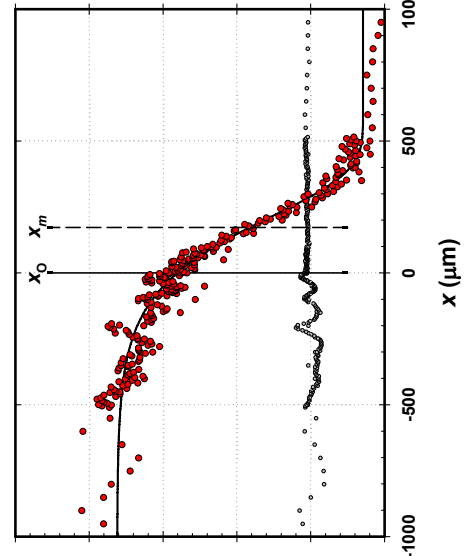
$x_m - x_0 = 186 \mu\text{m}$

8 / 2



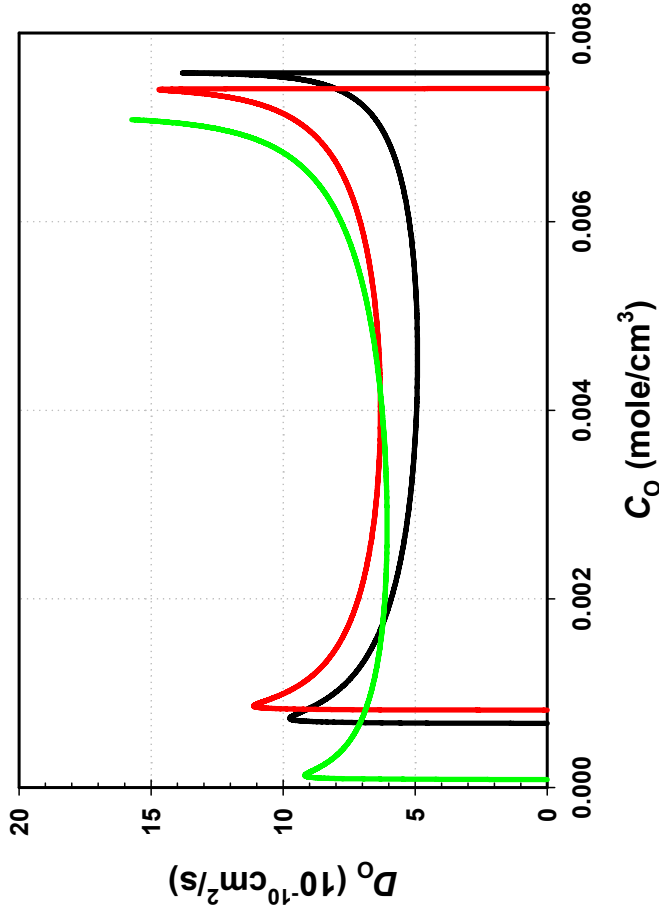
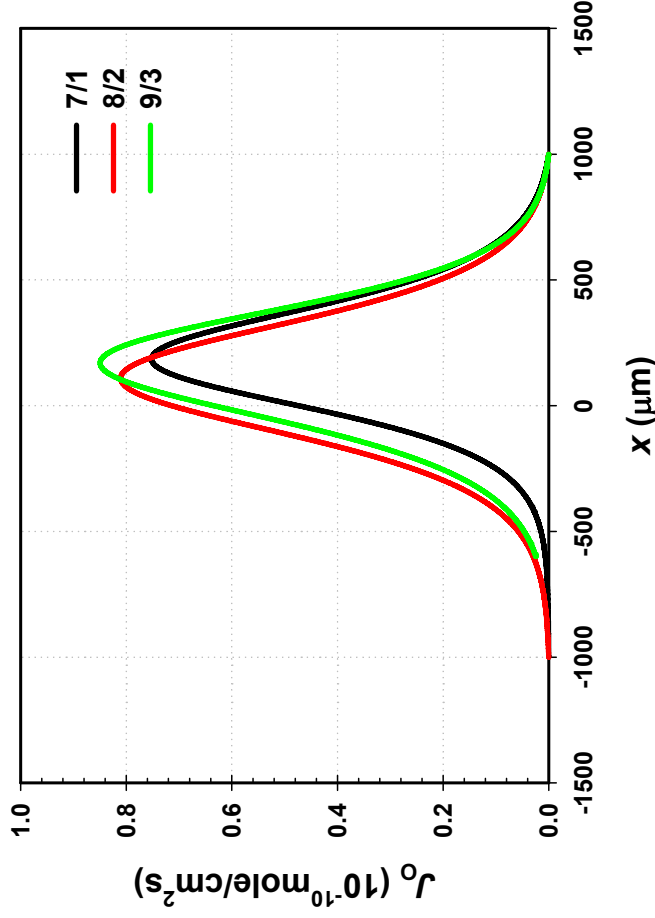
$x_m - x_0 = 109 \mu\text{m}$

9 / 3



$x_m - x_0 = 173 \mu\text{m}$

calculated J_O and \tilde{D}_{Oo}

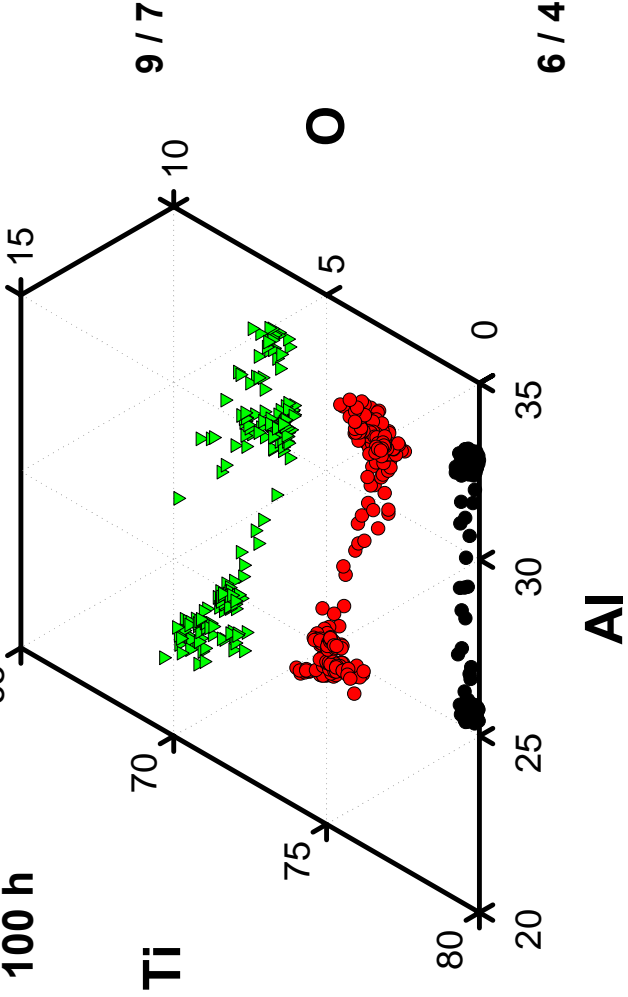


alloy	Ti-Al / Al ₂ O ₃ couples		$\alpha_2(O) / \alpha_2(O)$ couples	
	\tilde{D}_{Oo} (10^{-10} cm ² /s) $T = 1100^\circ\text{C}$	Ti / Al (couple)	\tilde{D}_{Oo} (10^{-10} cm ² /s) $T = 1100^\circ\text{C}$	
Ti-25Al	4.0 ± 1.0	2.9 (7 / 1)	4.8 ± 1.0	
Ti-32Al	5.5 ± 1.5	2.3 (8 / 2)	6.2 ± 1.5	
Ti-35Al	6.5 ± 1.5	2.0 (9 / 3)	6.1 ± 2.0	

$\tilde{D}_{Oo} \sim$ independent of X_O but small Ti / Al dependence (?)

$T = 1100^\circ\text{C}$,
100 h

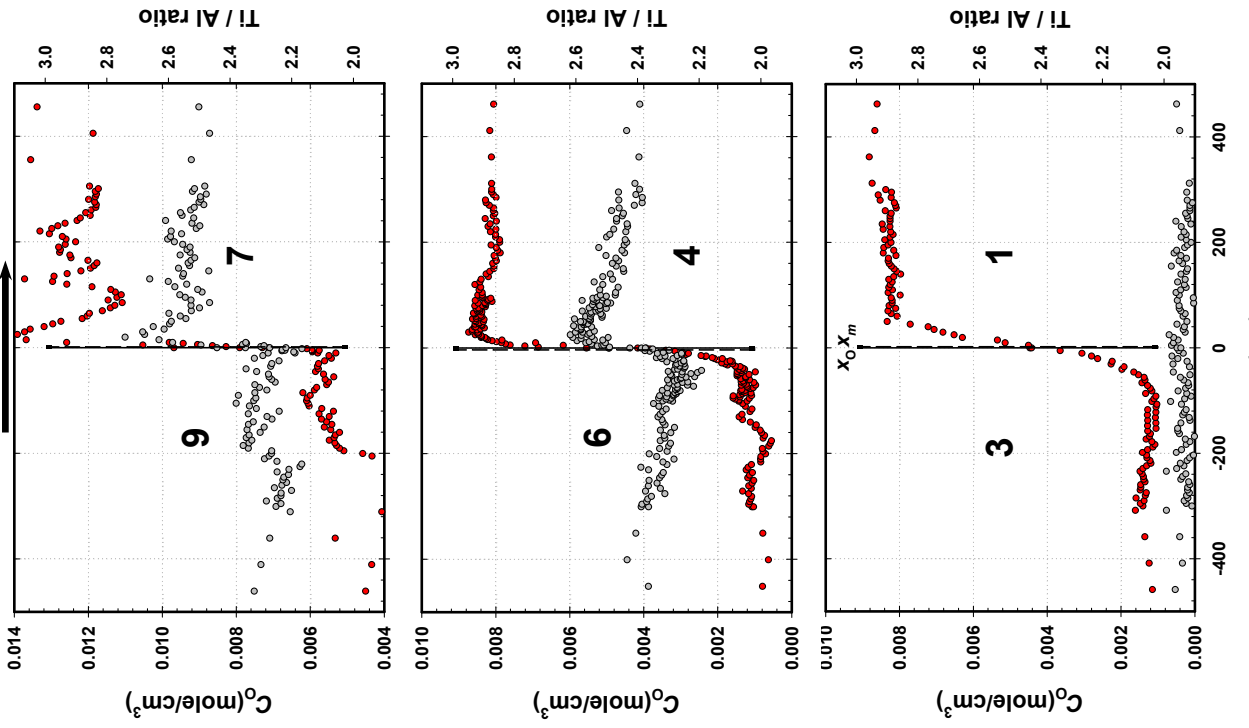
constant C_0



- profiles flipped relative to diffusion path
- classic “up-hill” profile for O...
- ↳ thermodynamic interaction: $\text{Ti-Al} \rightarrow \text{O}$
- Ti-Al interaction zone decreases with X_{O} 3 / 1
- ↳ $\text{O} \rightarrow \text{Ti-Al}$: kinetic / thermodynamic ?
- ↳ expect similar $\Delta\mu_{(\text{Ti,Al})}$ for each X_{O}

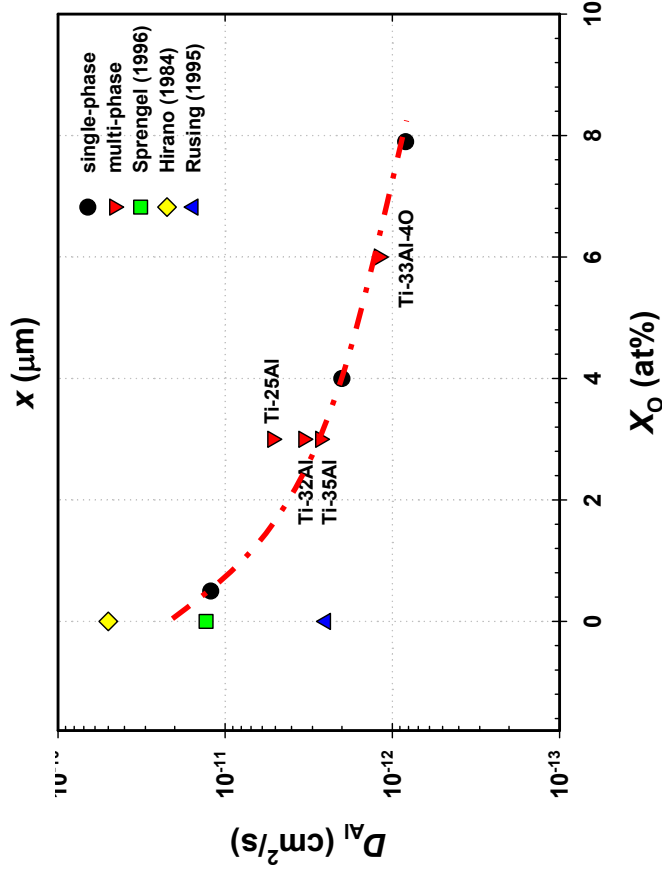
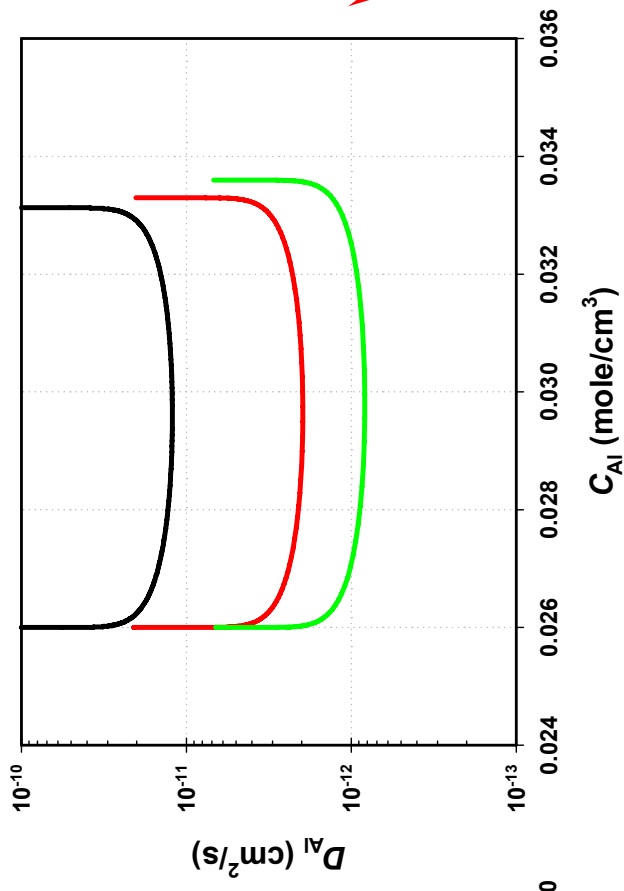
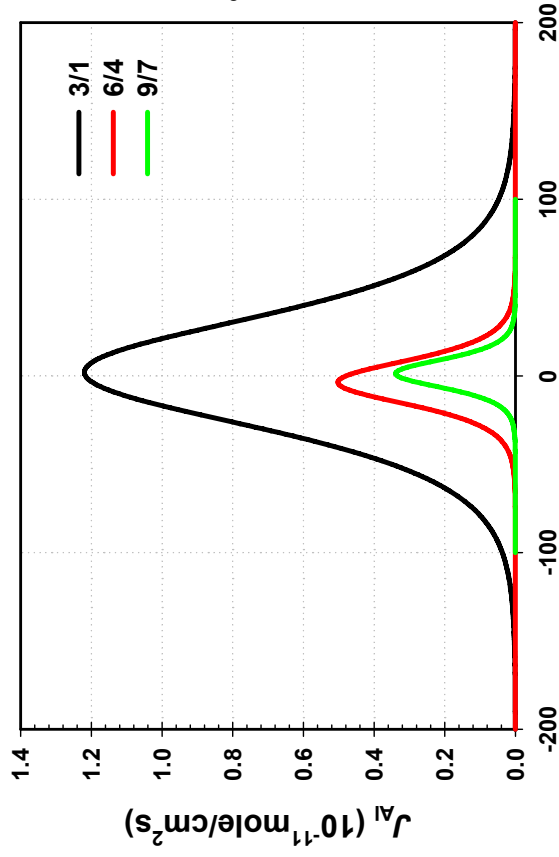


J_{Ti}
 $J_{\text{Al}} J_{\text{O}}$

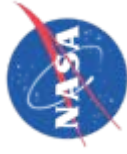




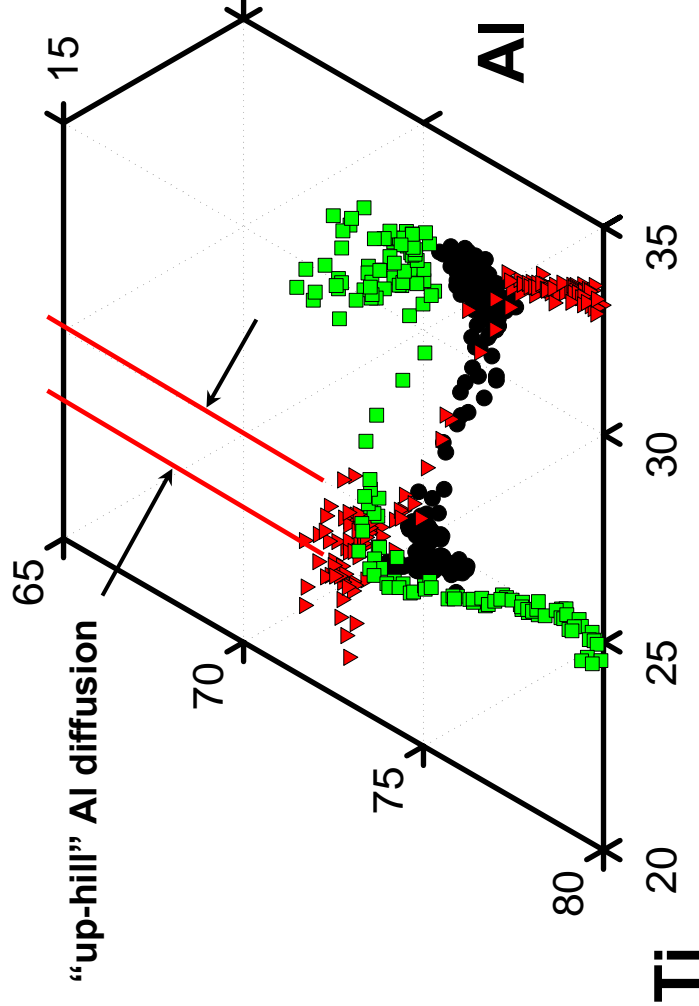
calculated \tilde{J}_{Al} and \tilde{D}_{Al}



- Ti-Al and O diffusion isn't independent
- X_O not controlled in previous studies:
 - ↳ Sprengel: SiO₂ capsules, no Ta-foil
 - ↳ Rusing: flowing Ar-atmosphere



“intersecting” paths: 9-1, 7-3, 6-4

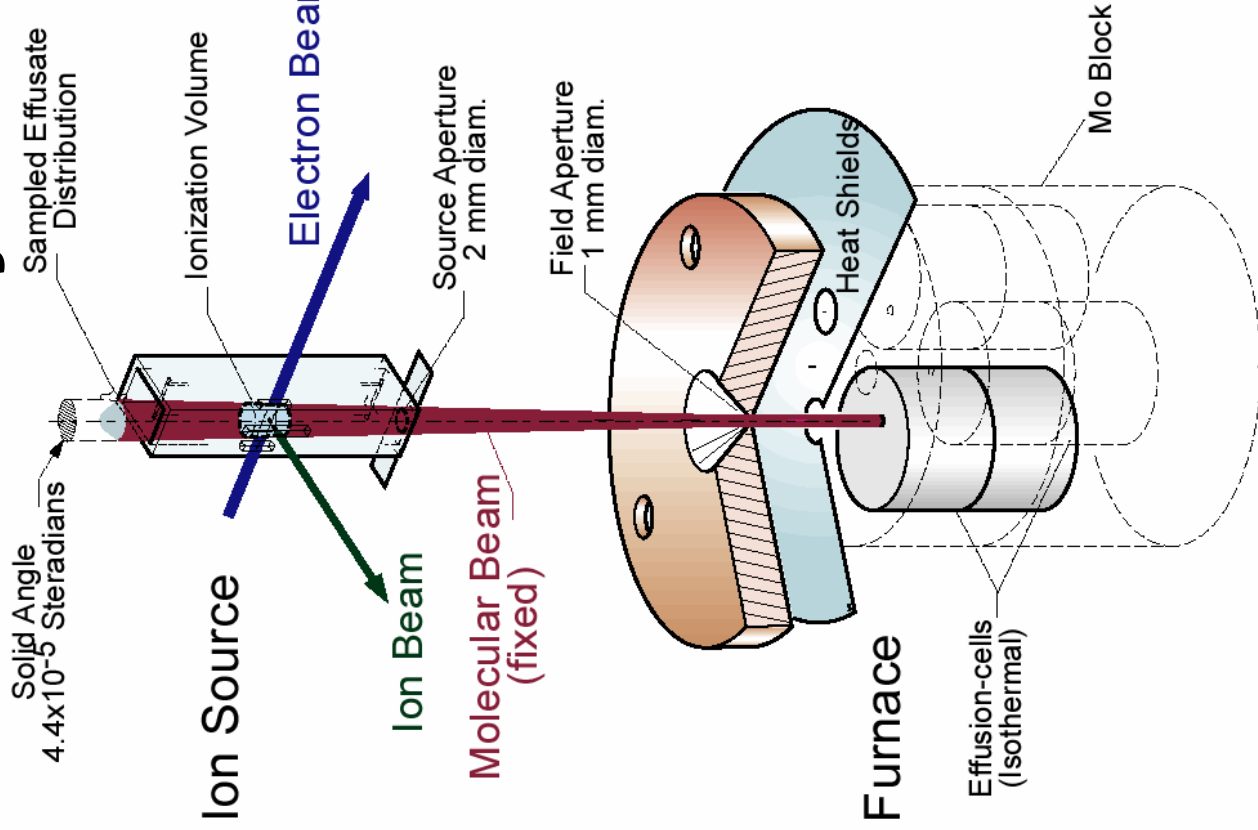


$$\tilde{J}_O^i = -\tilde{D}_{Oo}^{Ti} \frac{\partial C_O}{\partial x} - \tilde{D}_{OAl}^{Ti} \frac{\partial C_{Al}}{\partial x}$$

$$\tilde{J}_{Al}^i = -\tilde{D}_{AlO}^{Ti} \frac{\partial C_O}{\partial x} - \tilde{D}_{AlAl}^{Ti} \frac{\partial C_{Al}}{\partial x}$$

- 9-1 and 7-3 don't intersect; 7-3 and 6-4 are parallel...
- ↳ new couples needed to determine kinetic interaction $O \rightarrow Ti-Al$
- 9-1 diffusion path shows “up-hill” Al diffusion:
- ↳ O dissolution must: increase $a(Al)$, decrease $a(Ti)$ (or both)

thermodynamic measurements



multi-cell KEMS

pressure measurement

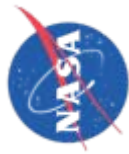
$$p(i) = I_{ik}^+ T / S_{ik}$$

activity measurement

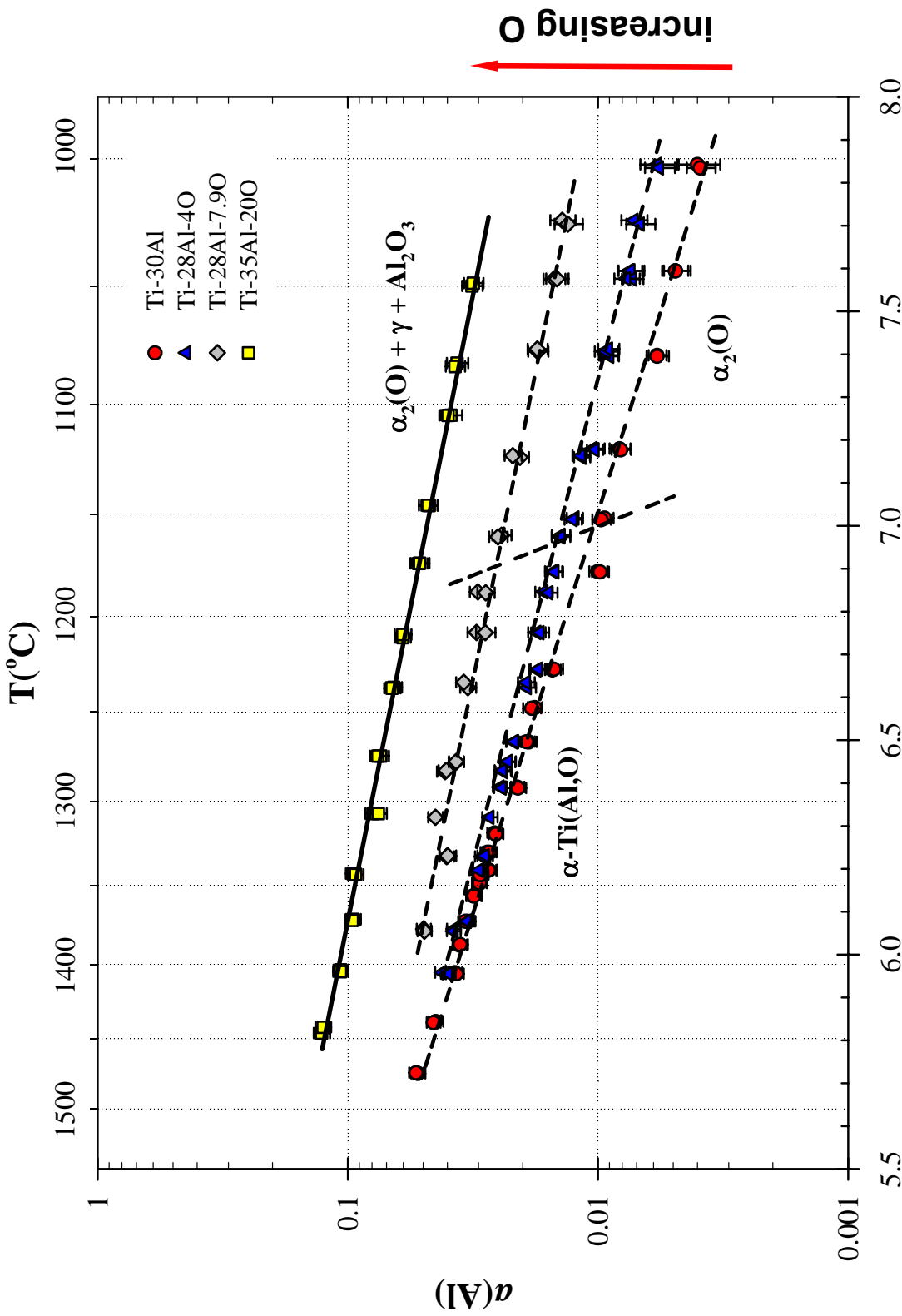
$$a(i) = \frac{p(i)}{p^\circ(i)} = \frac{I_i}{I_i^\circ}$$

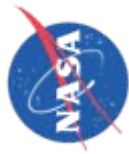
$$a(i) = \frac{p(i)}{\cancel{p^\circ(\text{Au})}} \cdot \left[\frac{\cancel{p^\circ(\text{Au})}}{p^\circ(i)} \right] = \frac{I_i}{I_{\text{Au}}^\circ} \cdot \left[\frac{S_{\text{Au}}}{S_i} \cdot \frac{g(R)}{g(A)} \cdot \left[\frac{p^\circ(\text{Au})}{p^\circ(i)} \right] \right]$$

(i = Ti, Al, Al₂O)

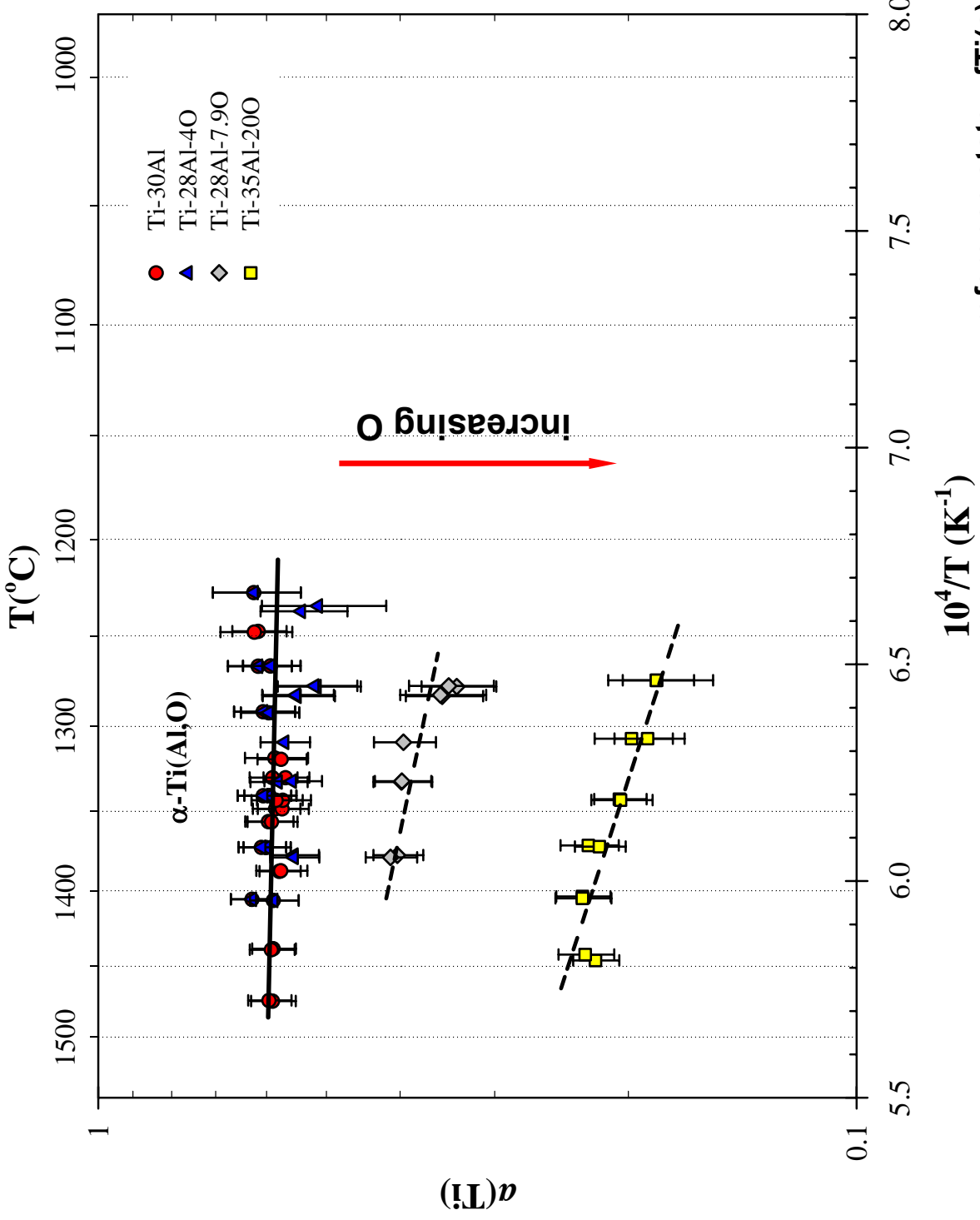


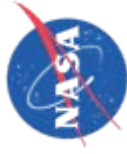
$a(\text{Al})$ vs. X_{O}





$a(\text{Ti})$ vs. X_{O}





summary

- $\alpha_2 / \text{Al}_2\text{O}_3$ and $\alpha_2(\text{O}) / \alpha_2(\text{O})$ couples... Ti-Al-O reaction behavior
- unsaturated $\alpha_2(\text{O})$ reduces Al_2O_3 : γ -layer, “up-hill” \tilde{J}_O in $\alpha_2(\text{O})$
- $\tilde{J}_\text{O} \gg \tilde{J}_\text{Al}$; treat subst. and interstitial lattices independently
 - ↳ Ti-Al “pseudo binary” $\tilde{D} = \tilde{D}(\text{C}_i)$, scatter in data (effect of X_O)
 - ↳ “transient equ.”: $\tilde{D}_{\text{OAl}} / \tilde{D}_{\text{Oo}}$ and \tilde{D}_{Oo} , slight Ti / Al dependence
- $\alpha_2(\text{O}) / \alpha_2(\text{O})$ couples: confirm $\tilde{D}_{\text{OAl}} / \tilde{D}_{\text{Oo}}$ and \tilde{D}_{Oo} behavior, but Ti-Al interdiffusion reduced $> 10x$ with $X_\text{O} 0.005 \rightarrow 0.08$
 - ↳ thermodynamic interaction + change in mobility (?)
 - ↳ difficult to observe kinetic aspect; thermodynamics is clear
- more work is need...
 - ↳ significant insight to oxidation of Ti-Al alloys

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